

NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

NPN Darlington Power Transistor

This high voltage power Darlington has been specifically designed for inductive applications such as Electronic Ignition, Switching Regulators and Motor Control.

Features

- Exceptional Safe Operating Area
- High V_{CE} ; High Current Gain
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices*

Benefits

- Reliable Performance at Higher Powers
- Designed for Inductive Loads
- Very Low Current Requirements

Applications

- Internal Combustion Engine Ignition Control
- Switching Regulators
- Motor Controls
- Light Ballast
- Photo Flash

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V_{CEO}	350	Vdc
Collector-Base Breakdown Voltage	V_{CBO}	700	Vdc
Collector-Emitter Breakdown Voltage	V_{CES}	700	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current Continuous Peak	I_C I_{CM}	4.0 8.0	Adc
Base Current	I_B	0.5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	45 0.36	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

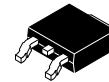
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

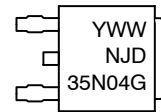
<http://onsemi.com>

**DARLINGTON
POWER TRANSISTORS**
4 AMPERES
350 VOLTS
45 WATTS



DPAK
CASE 369C
STYLE 1

MARKING DIAGRAM



Y = Year
WW = Work Week
NJD35N04 = Device Code
G = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping†
NJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJVNJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
NJVNJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	2.78	$^{\circ}\text{C}/\text{W}$
Junction-to-Ambient	$R_{\theta JA}$	71.4	

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ($I_C = 10\text{ mA}$, $L = 10\text{ mH}$)	$V_{CEO(sus)}$	350	-	-	V
Collector Cutoff Current ($V_{CE} = 500\text{ V}$) ($I_B = 0$) ($V_{CE} = 500\text{ V}$, $T_C = 125^{\circ}\text{C}$)	I_{CES}	-	-	50 250	μA
Collector Cutoff Current ($V_{CE} = 250\text{ V}$) ($I_B = 0$) ($V_{CE} = 200\text{ V}$, $T_C = 125^{\circ}\text{C}$)	I_{CEO}	-	-	50 250	μA
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$)	I_{EBO}	-	-	5.0	μA

ON CHARACTERISTICS

Collector-Emitter Saturation Voltage ($I_C = 2.0\text{ A}$, $I_B = 20\text{ mA}$) ($I_C = 2.0\text{ A}$, $I_B = 20\text{ mA}$ 125°C)	$V_{CE(sat)}$	-	-	1.5 1.5	V
Base-Emitter Saturation Voltage ($I_C = 2.0\text{ A}$, $I_B = 20\text{ mA}$) ($I_C = 2.0\text{ A}$, $I_B = 20\text{ mA}$ 125°C)	$V_{BE(sat)}$	-	-	2.0 2.0	V
Base-Emitter On Voltage ($I_C = 2.0\text{ A}$, $V_{CE} = 2.0\text{ V}$) ($I_C = 2.0\text{ A}$, $V_{CE} = 2.0\text{ V}$] 25°C)	$V_{BE(on)}$	-	-	2.0 2.0	V
DC Current Gain ($I_C = 2.0\text{ A}$, $V_{CE} = 2.0\text{ V}$) ($I_C = 4.0\text{ A}$, $V_{CE} = 2.0\text{ Vdc}$)	h_{FE}	2000 300	-	-	-

DYNAMIC CHARACTERISTICS

Current-Gain - Bandwidth Product ($I_C = 2.0\text{ A}$, $V_{CE} = 10\text{ V}$, $f = 1.0\text{ MHz}$)	f_T	90	-	-	MHz
Output Capacitance ($V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 0.1\text{ MHz}$)	C_{ob}	-	60	-	pF

SWITCHING CHARACTERISTICS

$V_{CC} = 12\text{ V}$, $V_{clamp} = 250\text{ V}$, $L = 4\text{ mH}$ $I_C = 2\text{ A}$, $I_{B1} = 20\text{ mA}$, $I_{B2} = -20\text{ mA}$	t_s t_f	-	18 0.8	-	μSec
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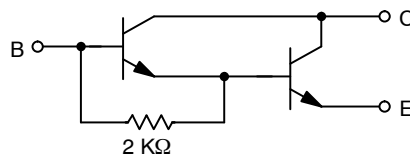


Figure 1. Darlington Circuit Schematic

TYPICAL CHARACTERISTICS

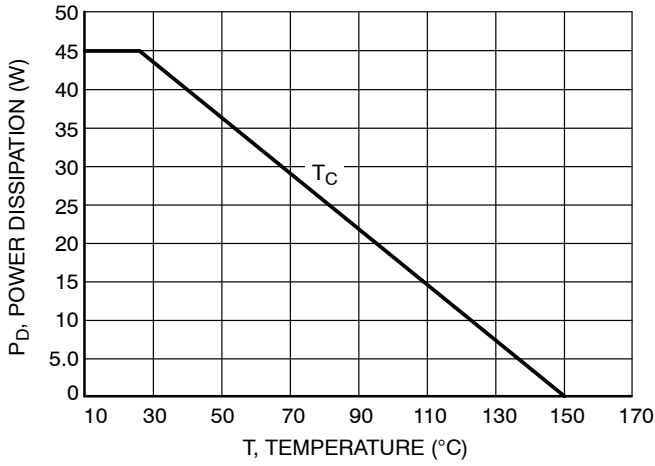


Figure 2. Power Derating

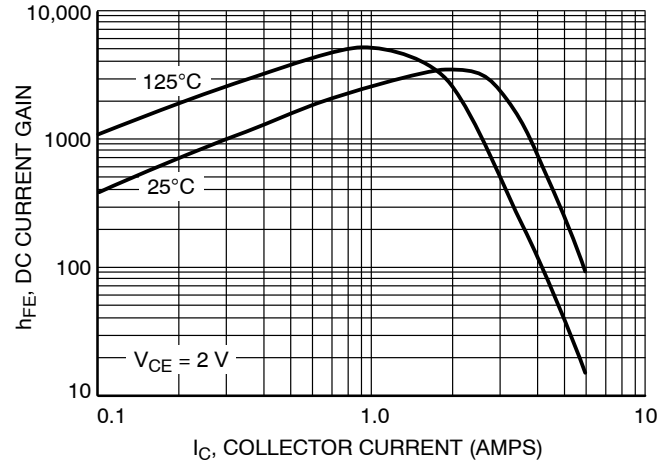


Figure 3. DC Current Gain

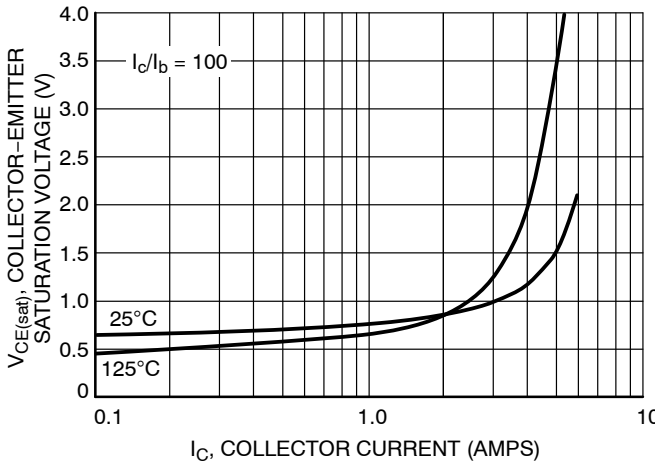


Figure 4. Collector-Emitter Saturation Voltage

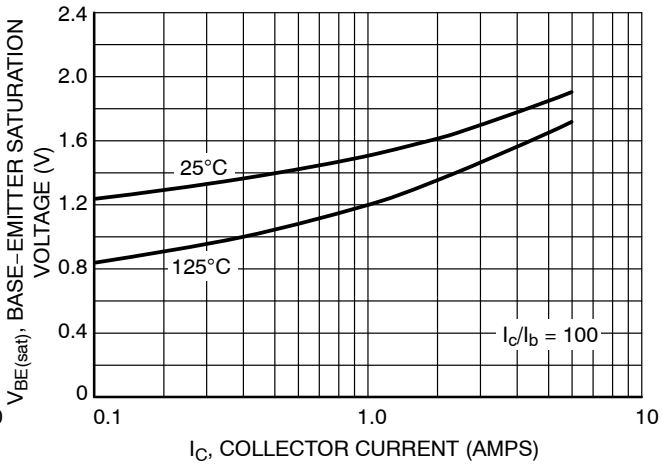


Figure 5. Base-Emitter Saturation Voltage

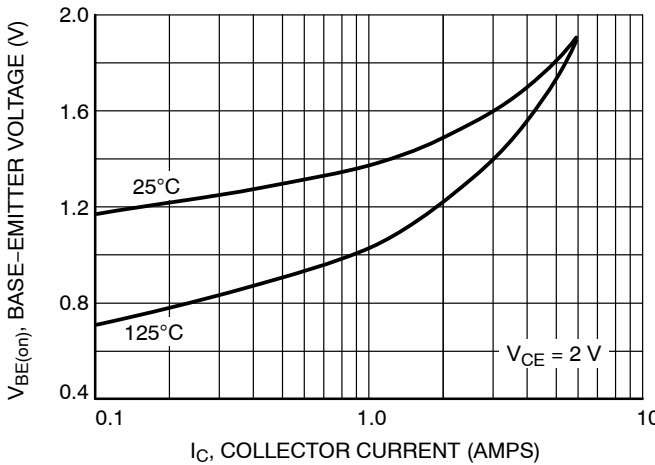


Figure 6. Base-Emitter Voltage

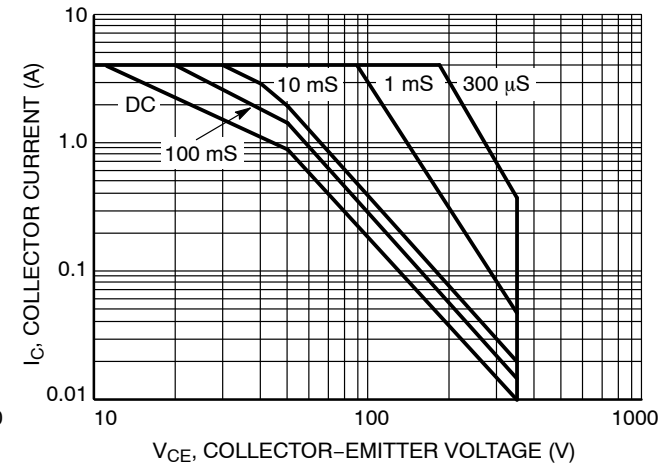
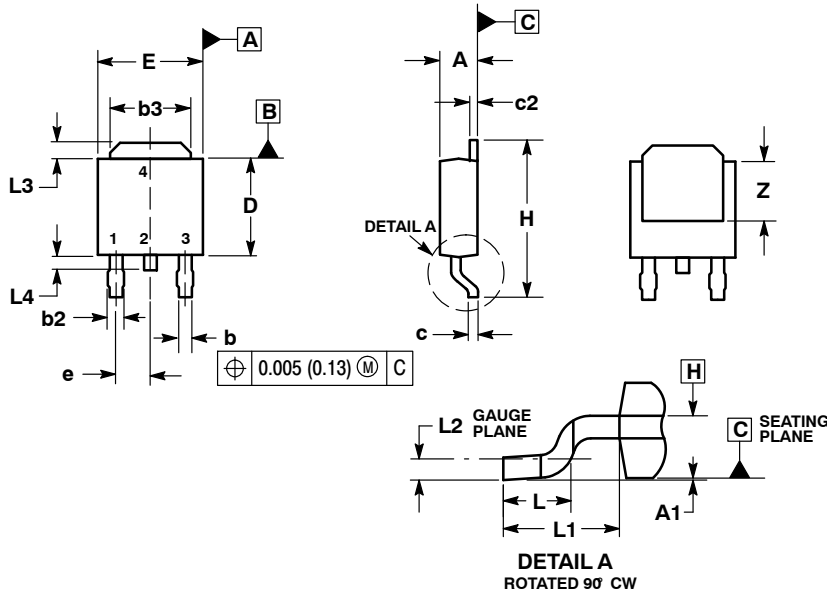


Figure 7. Forward Bias Safe Operating Area (FBSOA)

NJD35N04G, NJVJND35N04G, NJVJND35N04T4G

PACKAGE DIMENSIONS

DPAK
CASE 369C-01
ISSUE D

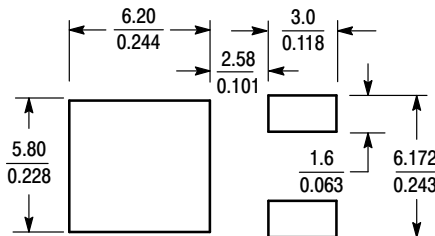


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

SOLDERING FOOTPRINT*



SCALE 3:1 (mm/inches)

STYLE 1:

1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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